# NSN 5961-01-209-2295

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## Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

0.450 inches

# Overall Width:

1.050 inches

# Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

140.0 collector to base voltage, dc and 140.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, dc

#### **Current Rating Per Characteristic:**

12.00 amperes source cutoff current

#### Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

35.0 degrees celsius ambient air

## **Special Features:**

Junction pattern arrangement: pnp

## Terminal Type And Quantity:

2 pin and 1 case

## Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

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